

PC3Q65J0000F Series

*1-channel package type is also available. (model No. **PC3H5J0000F Series**)

Mini-flat Half Pitch 4-channel Package Darlington Phototransistor Output Photocoupler



■ Description

PC3Q65J0000F Series contains an IRED optically coupled to a phototransistor.

It is packaged in a 4 channel Mini-flat, Half pitch type.

Input-output isolation voltage(rms) is 2.5kV. CTR is MIN. 600% at input current of 1mA.

■ Features

- 1. 4 channel Mini-flat Half pitch package (Lead pitch : 1.27mm)
- 2. Double transfer mold package (Ideal for Flow Soldering)
- 3. Darlington phototransistor output (CTR : MIN. 600% at I_F=1mA, V_{CE}=2V)
- 4. Isolation voltage between input and output $(V_{iso(rms)}=2.5kV)$
- 5. Lead-free and RoHS directive compliant

■ Agency approvals/Compliance

- 1. Recognized by UL1577 (Double protection isolation), file No. E64380 (as model No. **PC3Q65**)
- 2. Approved by VDE, DIN EN60747-5-2^(*) (as an option), file No. 40009162 (as model No. **PC3Q65**)
- 3. Package resin: UL flammability grade (94V-0)

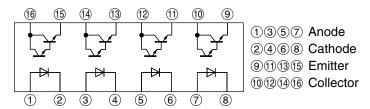
Applications

- 1. Programmable controllers
- 2. Facsimiles
- 3. Telephones

^(*)DIN EN60747-5-2: successor standard of DIN VDE0884

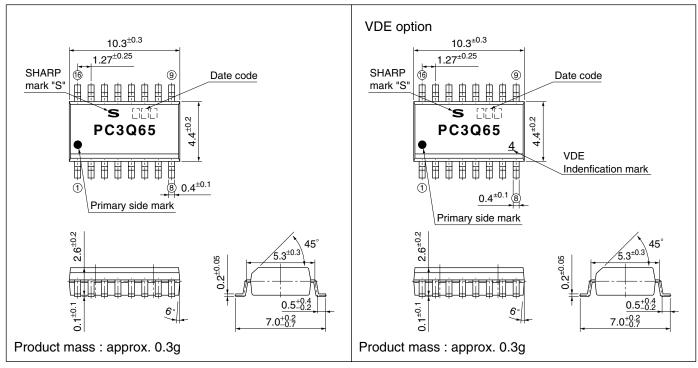


■ Internal Connection Diagram



■ Outline Dimensions

(Unit: mm)



Plating material: SnCu (Cu: TYP. 2%)



Date code (3 digit)

1st digit				2nd digit		3rd digit	
Year of production				Month of production		Week of production	
A.D.	Mark	A.D	Mark	Month	Mark	Week	Mark
1990	A	2002	P	January	1	1st	1
1991	В	2003	R	February	2	2nd	2
1992	С	2004	S	March	3	3rd	3
1993	D	2005	T	April	4	4th	4
1994	Е	2006	U	May	5	5, 6th	5
1995	F	2007	V	June	6		
1996	Н	2008	W	July	7		
1997	J	2009	X	August	8		
1998	K	2010	A	September	9		
1999	L	2011	В	October	0		
2000	M	2012	С	November	N		
2001	N	:	:	December	D		

repeats in a 20 year cycle

Country of origin Japan

Rank mark

There is no rank mark indicator.



■ Absolute Maximum Ratings

Absolute Maximum Ratings (T _a =25°C						
	Parameter	Symbol	Rating	Unit		
	Forward current	I_{F}	50	mA		
Input	*1 Peak forward current	I_{FM}	1	A		
Inj	Reverse voltage	V_R	6	V		
	Power dissipation	P	70	mW		
	Collector-emitter voltage	V_{CEO}	35	V		
Output	Emitter-collector voltage	V_{ECO}	6	V		
Out	Collector current	I_C	80	mA		
	Collector power dissipation	P_{C}	150	mW		
Total power dissipation		P_{tot}	170	mW		
	Operating temperature	T_{opr}	-30 to +100	°C		
	Storage temperature	T_{stg}	-40 to +125	°C		
*2 Isolation voltage		$V_{iso(rms)}$	2.5	kV		
*3 (Soldering temperature	T_{sol}	260	°C		

^{*1} Pulse width≤100μs, Duty ratio : 0.001 *2 40 to 60%RH, AC for 1 minute, f=60Hz *3 For 10s

■ Electro-optical Characteristics

 $(T_a=25^{\circ}C)$

· · · · · · · · · · · · · · · · · · ·								
Parameter		Symbol	Conditions	MIN.	TYP.	MAX.	Unit	
Input	Forward voltage		V_F	$I_F=20mA$	_	1.2	1.4	V
	Reverse current		I_R	$V_R=4V$	_	_	10	μΑ
	Terminal capacitance		C_{t}	V=0, f=1kHz	-	30	250	pF
	Collector dark current		I_{CEO}	$V_{CE}=10V, I_{F}=0$	_	_	1000	nA
Output	Collector-emitter breakdown voltage		BV_{CEO}	$I_{C}=0.1 \text{ mA}, I_{F}=0$	35	_	_	V
	Emitter-collector breakdown voltage		BV_{ECO}	$I_E=10\mu A, I_F=0$	6	-	-	V
Transfer characteristics	Collector current		I_C	$I_F=1mA$, $V_{CE}=2V$	6	16	75	mA
	Collector-emitter saturation voltage		V _{CE (sat)}	$I_F=1mA$, $I_C=2mA$	_	0.8	1.0	V
	Isolation resistance		R_{ISO}	DC500V, 40 to 60%RH	5×10 ¹⁰	1×10 ¹¹	_	Ω
	Floating capacitance		C_{f}	V=0, $f=1MHz$	_	0.6	1.0	pF
	Response time	Rise time	t _r	V_{CE} =2V, I_C =2mA, R_L =100 Ω	_	60	300	μs
		Fall time	t_{f}		_	53	250	μs



■ Model Line-up

Package	Taping			
rackage	1 000pcs/reel			
DIN EN60747-5-2		Approved		
Model No.	PC3Q65J0000F	PC3Q65YJ000F		

Please contact a local SHARP sales representative to inquire about production status.



Fig.1 Forward Current vs. Ambient Temperature

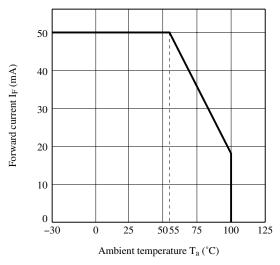


Fig.3 Collector Power Dissipation vs. Ambient Temperature

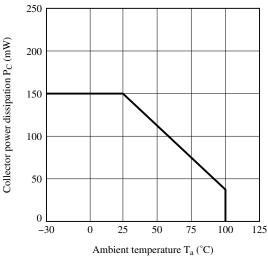


Fig.5 Peak Forward Current vs. Duty Ratio

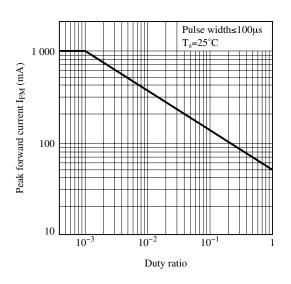


Fig.2 Diode Power Dissipation vs.
Ambient Temperature

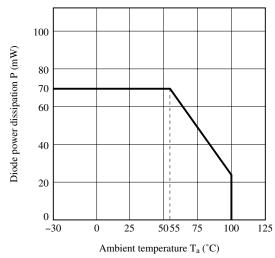


Fig.4 Total Power Dissipation vs. Ambient Temperature

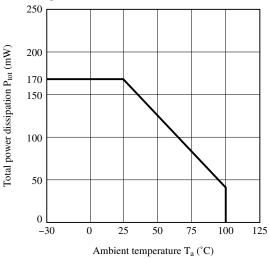


Fig.6 Forward Current vs. Forward Voltage

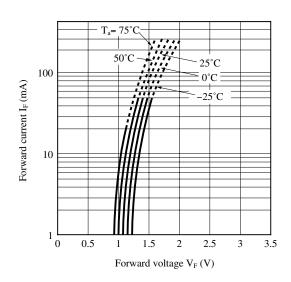




Fig.7 Current Transfer Ratio vs. Forward Current

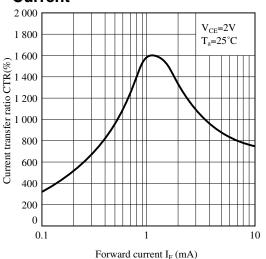


Fig.9 Relative Current Transfer Ratio vs.

Ambient Temperature

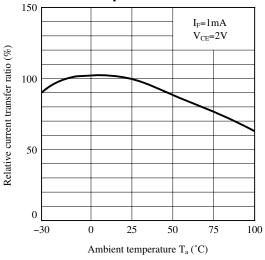


Fig.11 Collector Dark Current vs. Ambient Temperature

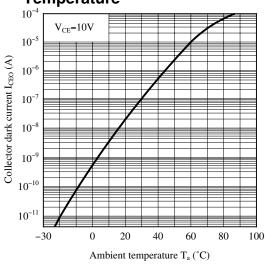


Fig.8 Collector Current vs. Collector-emitter Voltage

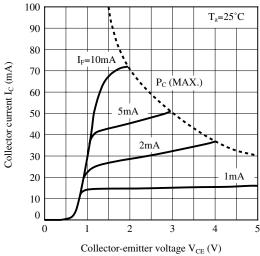


Fig.10 Collector - emitter Saturation Voltage vs. Ambient Temperature

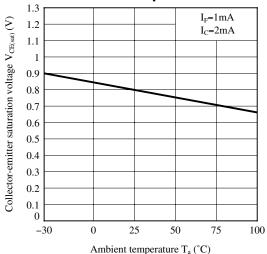
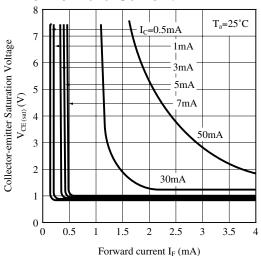


Fig.12 Collector-emitter Saturation Voltage vs. Forward Current



Remarks: Please be aware that all data in the graph are just for reference and not for guarantee.



■ Design Considerations

Design guide

While operating at I_F<1.0mA, CTR variation may increase.

Please make design considering this fact.

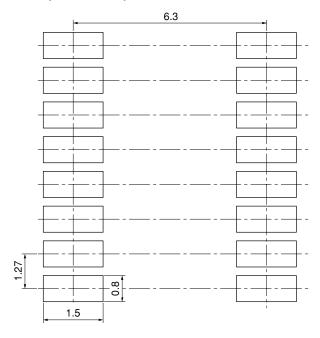
This product is not designed against irradiation and incorporates non-coherent IRED.

Degradation

In general, the emission of the IRED used in photocouplers will degrade over time.

In the case of long term operation, please take the general IRED degradation (50% degradation over 5 years) into the design consideration.

Recommended Foot Print (reference)



(Unit: mm)

[☆] For additional design assistance, please review our corresponding Optoelectronic Application Notes.



■ Manufacturing Guidelines

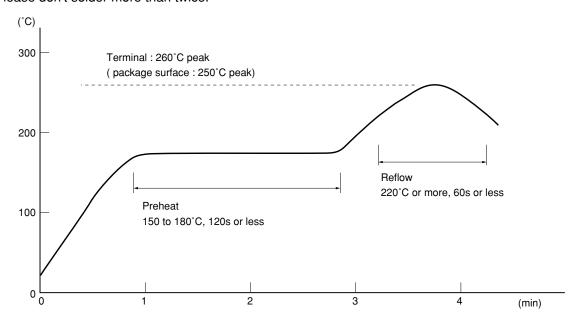
Soldering Method

Reflow Soldering:

Reflow soldering should follow the temperature profile shown below.

Soldering should not exceed the curve of temperature profile and time.

Please don't solder more than twice.



Flow Soldering:

Due to SHARP's double transfer mold construction submersion in flow solder bath is allowed under the below listed guidelines.

Flow soldering should be completed below 260°C and within 10s.

Preheating is within the bounds of 100 to 150°C and 30 to 80s.

Please don't solder more than twice.

Hand soldering

Hand soldering should be completed within 3s when the point of solder iron is below 400°C.

Please don't solder more than twice.

Other notices

Please test the soldering method in actual condition and make sure the soldering works fine, since the impact on the junction between the device and PCB varies depending on the tooling and soldering conditions.



Cleaning instructions

Solvent cleaning:

Solvent temperature should be 45°C or below Immersion time should be 3 minutes or less

Ultrasonic cleaning:

The impact on the device varies depending on the size of the cleaning bath, ultrasonic output, cleaning time, size of PCB and mounting method of the device.

Therefore, please make sure the device withstands the ultrasonic cleaning in actual conditions in advance of mass production.

Recommended solvent materials:

Ethyl alcohol, Methyl alcohol and Isopropyl alcohol

In case the other type of solvent materials are intended to be used, please make sure they work fine in actual using conditions since some materials may erode the packaging resin.

Presence of ODC

This product shall not contain the following materials.

And they are not used in the production process for this product.

Regulation substances: CFCs, Halon, Carbon tetrachloride, 1.1.1-Trichloroethane (Methylchloroform)

Specific brominated flame retardants such as the PBBOs and PBBs are not used in this product at all.

This product shall not contain the following materials banned in the RoHS Directive (2002/95/EC).

•Lead, Mercury, Cadmium, Hexavalent chromium, Polybrominated biphenyls (PBB), Polybrominated diphenyl ethers (PBDE).

Sheet No.: D2-A01802EN



■ Package specification

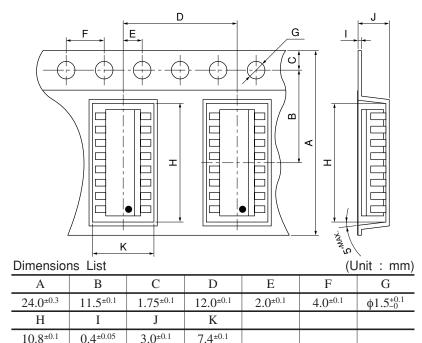
● Tape and Reel package

Package materials
Carrier tape : PS

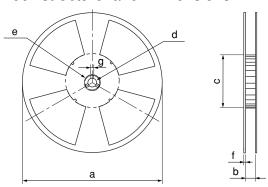
Cover tape: PET (three layer system)

Reel: PS

Carrier tape structure and Dimensions

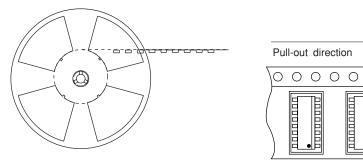


Reel structure and Dimensions



Dimensio	ns List	(Unit: mm)		
a	b	с	d	
330	25.5±1.5	100±1.0	13 ^{±0.5}	
e	f	g		
23±1.0	2.0±0.5	2.0±0.5		

Direction of product insertion



[Packing: 1 000pcs/reel]



■ Important Notices

- · The circuit application examples in this publication are provided to explain representative applications of SHARP devices and are not intended to guarantee any circuit design or license any intellectual property rights. SHARP takes no responsibility for any problems related to any intellectual property right of a third party resulting from the use of SHARP's devices.
- · Contact SHARP in order to obtain the latest device specification sheets before using any SHARP device. SHARP reserves the right to make changes in the specifications, characteristics, data, materials, structure, and other contents described herein at any time without notice in order to improve design or reliability. Manufacturing locations are also subject to change without notice.
- · Observe the following points when using any devices in this publication. SHARP takes no responsibility for damage caused by improper use of the devices which does not meet the conditions and absolute maximum ratings to be used specified in the relevant specification sheet nor meet the following conditions:
- (i) The devices in this publication are designed for use in general electronic equipment designs such as:
 - --- Personal computers
 - --- Office automation equipment
 - --- Telecommunication equipment [terminal]
 - --- Test and measurement equipment
 - --- Industrial control
 - --- Audio visual equipment
 - --- Consumer electronics
- (ii) Measures such as fail-safe function and redundant design should be taken to ensure reliability and safety when SHARP devices are used for or in connection

with equipment that requires higher reliability such as:

- --- Transportation control and safety equipment (i.e., aircraft, trains, automobiles, etc.)
- --- Traffic signals
- --- Gas leakage sensor breakers
- --- Alarm equipment
- --- Various safety devices, etc.
- (iii) SHARP devices shall not be used for or in connection with equipment that requires an extremely high level of reliability and safety such as:
 - --- Space applications
 - --- Telecommunication equipment [trunk lines]
 - --- Nuclear power control equipment
 - --- Medical and other life support equipment (e.g., scuba).
- · If the SHARP devices listed in this publication fall within the scope of strategic products described in the Foreign Exchange and Foreign Trade Law of Japan, it is necessary to obtain approval to export such SHARP devices.
- This publication is the proprietary product of SHARP and is copyrighted, with all rights reserved. Under the copyright laws, no part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, for any purpose, in whole or in part, without the express written permission of SHARP. Express written permission is also required before any use of this publication may be made by a third party.
- \cdot Contact and consult with a SHARP representative if there are any questions about the contents of this publication.

[E209] Sheet No.: D2-A01802EN